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FAIRCHILD

NC7SZ373 TinyLogic® UHS D-Type Latch with 3-STATE Output

General Description

Features

- Space saving SC70 6-lead package
- Ultra small MicroPak[™] leadless package
- Ultra High Speed; t_{PD} 2.6 ns Typ into 50 pF at 5V V_{CC}

- High Output Drive; ±24 mA at 3V V_{CC}
- Broad V_{CC} Operating Range; 1.65V to 5.5V
- Matches the performance of LCX when operated at $3.3V V_{CC}$
- Power down high impedance inputs/output
- Overvoltage tolerant inputs facilitate 5V to 3V translation
- Patented noise/EMI reduction circuitry implemented

Ordering Code:

Ordering Order Number	Code: Package Number	Product Code Top Mark	Package Description	Supplied As
General D The NC7SZ373 CMOS Latch wi High Speed Se SC70 6-lead p advanced CMOS with high output dissipation over device is specifie The inputs and o Inputs tolerate vo ating voltage. Th when Latch Ena data that meets i	73 ic ® UH escription s a single posi h 3-STATE ou ies of TinyLog ackage. The c b technology to drive while ma a very broad v dto operate ove utput are high ir ittages up to 7V he latch appear ole (LE) is HIG he setup time is		ild's Ultra = Ultra small MicroPak™ lead e saving ated with gh speed = High Output Drive; ±24 mA = Broad V _{CC} Operating Rang mge. The 5V range. / _{CC} is 0V. / _{CC} oper- the data LOW, the Brate and the performance of 3.3V V _{CC} = Power down high impedance = Overvoltage tolerant inputs = Patented noise/EMI reducti	package dless package as Typ into 50 pF at 5V V _{CC} at 3V V _{CC} ge; 1.65V to 5.5V of LCX when operated at ce inputs/output facilitate 5V to 3V translation

TinyLogic® is a registered trademark of Fairchild Semiconductor Corporation. MicroPak™ is a trademark of Fairchild Semiconductor Corporation.

NC7SZ373

Logic Symbol

Pin Descriptions

Pin Names	Description
D	Data Input
LE	Latch Enable Input
OE	Output Enable Input
Q	Latch Output

Function Table

		Output		
	LE	D	OE	Q
	Н	L	L	L
	Н	Н	L	Н
	L	Х	L	Q _{n-1}
	Х	Х	н	Z
HIGH	Logic Level	X = Immate	rial	

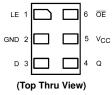
H = HIGH Logic Level X = Immaterial L = LOW Logic Level Z = HIGH Impedance

 Q_{n-1} = Previous state prior to HIGH-to-LOW transition of latch enable

AAA = Product Code Top Mark - see ordering code

Note: Orientation of Top Mark determines Pin One location. Read the top product code mark left to right, Pin One is the lower left pin.(see diagram).

Pad Assignments for MicroPak



Absolute Maximum Ratings(Note 1)								
Supply Voltage (V _{CC})	-0.5V to +7.0V							
DC Input Voltage (V _{IN})	-0.5V to +7.0V							
DC Output Voltage (V _{OUT})	-0.5V to +7.0V							
DC Input Diode Current (IIK)								
V _{IN} < 0V	–50 mA							
DC Output Diode Current (I _{OK})								
V _{OUT} < 0V	–50 mA							
DC Output (I _{OUT}) Source/Sink Current	±50 mA							
DC V _{CC} /GND Current (I _{CC} /I _{GND})	±50 mA							
Storage Temperature Range (T _{STG})	-65°C to +150°C							
Junction Temperature under Bias (T_J)	150°C							
Junction Lead Temperature (TL)								
(Soldering, 10 seconds)	260°C							
Power Dissipation (P _D) @+85°C	180 mW							

Recommended Operating Conditions (Note 2) Power Supply 1.65V to 5.5V Operating (V_{CC}) Data Retention 1.5V to 5.5V 0V to 5.5V Input Voltage (V_{IN}) Output Voltage (V_{OUT}) Active State 0V to V_{CC} 3-STATE 0V to 5.5V Input Rise and Fall Time (t_r, t_f) $V_{CC}=1.8V,\,2.5V\pm0.2V$ 0 to 20 ns/V $V_{CC}=3.3V\pm0.3V$ 0 to 10 ns/V $V_{CC}=5.5V\pm0.5V$ 0 to 5 ns/V Operating Temperature (T_A) -40°C to +85°C

NC7SZ373

350° C/W

Thermal Resistance (θ_{JA}) Note 1: The "Absolute Maximum Ratings": are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V _{cc}		$T_A = +25^{\circ}$	C	$T_A = -40^\circ$	C to +85°C	Unit	6	Conditions	
Symbol	Farameter	(V)	Min	Тур	Max	Min	Max	Unit	0	nutions	
VIH	HIGH Level Control	1.65 to 1.95	0.75 V _{CC}			0.75 V _{CC}		v			
	Input Voltage	2.3 to 5.5	0.7 V _{CC}			0.7 V _{CC}		v			
VIL	LOW Level Control	1.65 to 1.95			0.25 V _{CC}		0.25 V _{CC}	v			
	Input Voltage	2.3 to 5.5			0.3 V _{CC}		0.3 V _{CC}	v			
V _{OH}	HIGH Level Control	1.65	1.55	1.65		1.55					
	Output Voltage	1.8	1.7	1.8		1.7					
		2.3	2.2	2.3		2.2				$I_{OH} = -100 \ \mu A$	
		3.0	2.9	3.0		2.9					
		4.5	4.4	4.5		4.4		v	V V		
		1.65	1.24	1.52		1.29		• V V _{IN} =		$I_{OH} = -4 \text{ mA}$	
		2.3	1.9	2.15		1.9				$I_{OH} = -8 \text{ mA}$	
		3.0	2.4	2.8		2.4				$I_{OH} = -16 \text{ mA}$	
		3.0	2.3	2.68		2.3				$I_{OH} = -24 \text{ mA}$	
		4.5	3.8	4.2		3.8				$I_{OH} = -32 \text{ mA}$	
V _{OL}	LOW Level Control	1.65		0.0	0.08		0.0				
	Output Voltage	1.8		0.0	0.1		0.1				
		2.3		0.0	0.1		0.1			$I_{OL}=100\;\mu A$	
		3.0		0.0	0.1		0.1				
		4.5		0.0	0.1		0.1	v	V _V		
		1.65		0.08	0.24		0.24	v	$V_{IN} = V_{IL}$	$I_{OL} = 4 \text{ mA}$	
		2.3		0.10	0.3		0.3			$I_{OL} = 8 \text{ mA}$	
		3.0		0.15	0.4		0.4			$I_{OL} = 16 \text{ mA}$	
		3.0		0.22	0.55		0.55			$I_{OL} = 24 \text{ mA}$	
		4.5		0.22	0.55		0.55			$I_{OL} = 32 \text{ mA}$	
I _{IN}	Input Leakage Current	0 to 5.5			±0.1		±1.0	μA	$0 \leq V_{IN} \leq$	5.5V	
I _{OZ}	3-STATE	1.65 to 5.5			±0.5		±5.0	μA	$V_{\text{IN}} = V_{\text{IL}}$	or V _{IH}	
	Output Leakage	1.05 10 5.5			±0.5		±0.0	μΛ	$0 \leq V_{OUT}$	≤ 5.5V	
I _{OFF}	Power-Off Leakage Current	0.0			1.0		10	μA	V_{IN} or V_{O}	_{UT} = 5.5V	
I _{CC}	Quiescent Supply Current	1.65 to 5.5			1.0		10	μA	$V_{IN} = 5.5^{\circ}$	/, GND	

		V_{CC} $T_A = +25^{\circ}C$ T_A		$T_{A} = -40^{\circ}$	C to +85°C			Fig		
Symbol	Parameter	(V)	Min	Тур	Max	Min	Мах	Units	Conditions	Num
t _{PLH}	Propagation Delay	1.65	2.0	9.0	15.0	2.0	16.0			
t _{PHL}	D to Q	1.8	2.0	6.1	10.0	2.0	10.5			_
		2.5 ± 0.2	1.5	3.6	6.5	1.6	6.8		C _L = 15 pF	Figures
		3.3 ± 0.3	1.0	2.7	4.6	1.2	5.0	ns	$R_D = 1 M\Omega$.,
		5.0 ± 0.5	1.0	2.0	3.4	1.0	3.7		S ₁ = Open	
		3.3 ± 0.3	1.5	3.3	5.5	1.5	6.2		C _L = 50 pF	Figu
		5.0 ± 0.5	1.0	2.6	4.3	1.3	4.8		$R_D=500\Omega,\ S_1=Open$	Ĩ,
t _{PLH}	Propagation Delay	1.65	2.0	9.0	1.45	2.0	15.0			
t _{PHL}	LE to Q	1.8	2.0	6.0	9.6	2.0	10.0			_
		2.5 ± 0.2	1.8	3.5	6.1	1.5	6.6		C _L = 15 pF	Figu 1,
		$\textbf{3.3}\pm\textbf{0.3}$	1.3	2.6	4.4	1.0	4.8	ns	$R_D = 1 M\Omega$.,
		5.0 ± 0.5	1.0	2.0	3.2	0.8	3.5		S ₁ = Open	
		3.3 ± 0.3	1.5	3.3	5.3	1.5	6.2		$C_L = 50 \text{ pF}$	Figu
		5.0 ± 0.5	1.3	2.6	4.2	1.2	4.6		$R_D = 500\Omega, S_1 = Open$	1,
t _{PZL}	Output Enable Time	1.65	2.0	9.0	13.5	2.0	14.6			
t _{PZH}		1.8	2.0	6.0	9.0	2.0	9.5		$C_L = 50 \text{ pF}, V_I = 2x V_{CC}$	_
		2.5 ± 0.2	2.0	3.7	6.0	1.8	6.6	ns	$R_U, R_D = 500\Omega$	Figu 1,
		$\textbf{3.3}\pm\textbf{0.3}$	1.5	2.8	5.0	1.4	5.3		$S1 = GND$ for t_{PZH}	.,
		5.0 ± 0.5	1.0	2.2	3.7	1.0	3.9		$S1 = V_I$ for t_{PZL}	
t _{PLZ}	Output Disable Time	1.65	2.0	7.7	12.0	2.0	13.0			
t _{PHZ}		1.8	2.0	5.1	8.0	2.0	8.5		$C_L = 50 \text{ pF}, V_I = 2x V_{CC}$	-
		2.5 ± 0.2	2.0	3.5	6.0	1.8	6.3	ns	$R_U, R_D = 500\Omega$	Figu 1,
		3.3 ± 0.3	1.5	2.8	4.5	1.4	4.7		$S_1 = GND$ for t_{PHZ}	.,
		5.0 ± 0.5	1.0	2.3	3.7	1.0	3.9		$S_1 = V_I$ for t_{PLZ}	
t _S	Setup Time,	2.5 ± 0.2				2.0			$C_L = 50 \text{ pF}$	_ .
	D to LE	3.3 ± 0.3				1.5		ns	$R_D = 500 \ \Omega, \ S_1 = Open$	Figu 1,
		5.0 ± 0.5				1.5				.,
t _H	Hold Time,	2.5 ± 0.2				1.5			C _L = 50 pF	_ .
	D to LE	3.3 ± 0.3				1.5		ns	$R_D = 500 \; \Omega, \; S_1 = Open$	Figu 1,
		5.0 ± 0.5				1.5				.,
tw	Pulse Width, LE	2.5 ± 0.2				3.0				-
		3.3 ± 0.3				3.0		ns	$C_L = 50 \text{ pF}$	Figu 1,
		5.0 ± 0.5				3.0			$R_D = 500 \Omega$, $S_1 = Open$.,

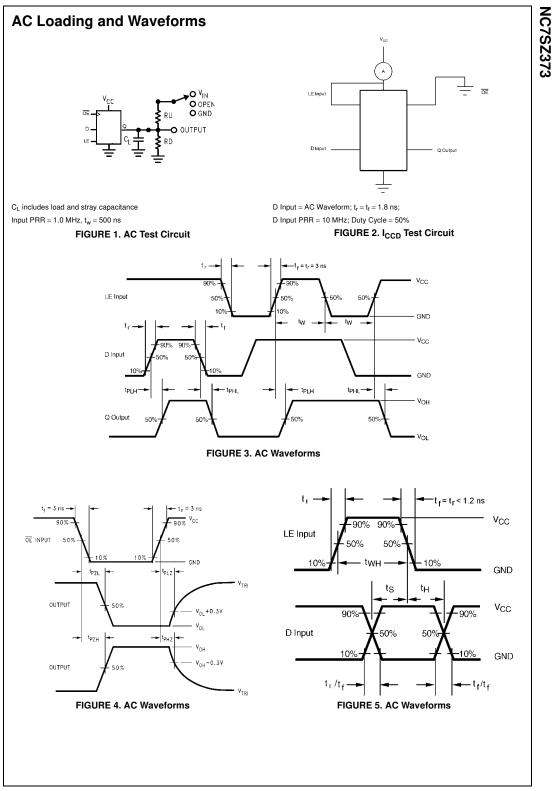
Capacitance (Note 3)

Symbol	Parameter	Тур	Max	Units	Conditions
C _{IN}	Input Capacitance	3		pF	$V_{CC} = Open, V_{IN} = 0V \text{ or } V_{CC}$
C _{OUT}	Output Capacitance	4		pF	V_{CC} = 3.3V, V_{IN} = 0V or V_{CC}
C _{PD}	Power Dissipation Capacitance	14		рF	$V_{CC} = 3.3V$
	(Note 4)	17		рі	$V_{CC} = 5.0V$

Note 3: $T_A = +25C$, f = 1 MHz.

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% output cycle. (See Figure 2) C_{PD} is related to I_{CCD} dynamic operating current by the expression:

 $\mathsf{I}_{CCD} = (\mathsf{C}_{PD})(\mathsf{V}_{CC})(\mathsf{f}_{\mathsf{IN}}) + (\mathsf{I}_{CC}\mathsf{static}).$





Tape and Reel Specification ____ 0070

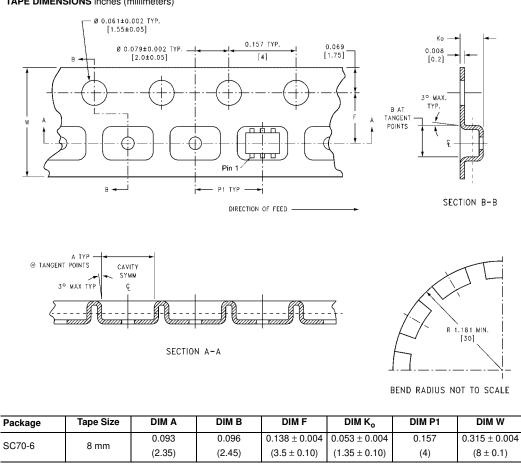
TAPE FORMAT for SC70								
Package	Таре	Number						
Decignotor	Continn	Covition						

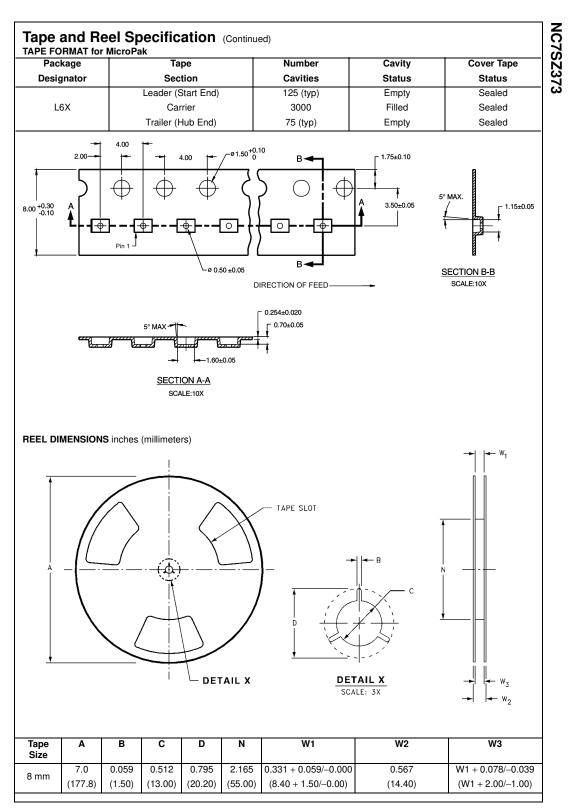
Designator	Section	Cavities	Status	Status
	Leader (Start End)	125 (typ)	Empty	Sealed
P6X	Carrier	3000	Filled	Sealed
	Trailer (Hub End)	75 (typ)	Empty	Sealed

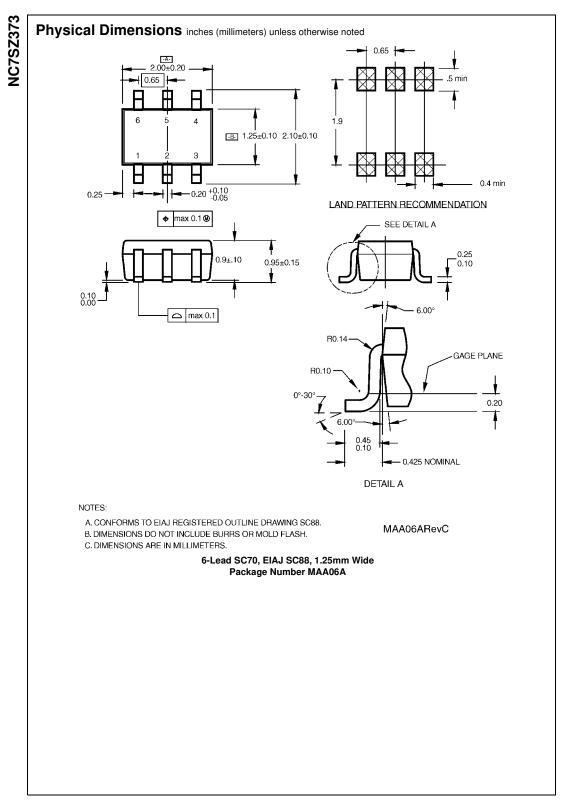
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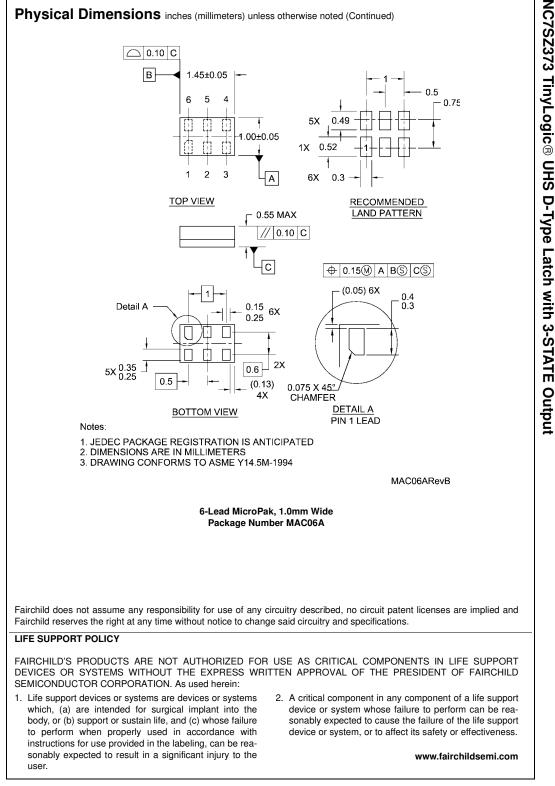
Cover Tape

TAPE DIMENSIONS inches (millimeters)









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